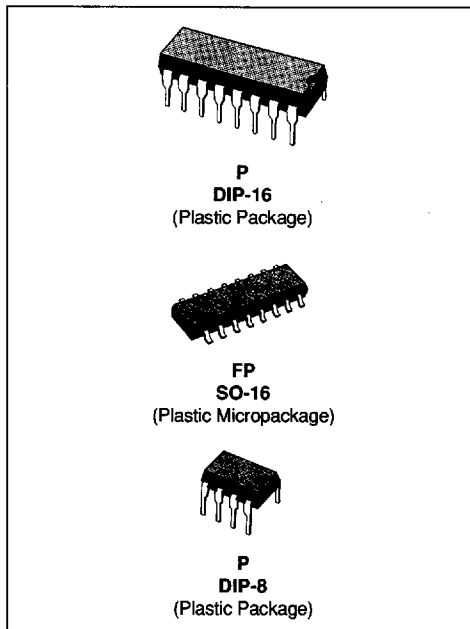


T-64-05

SWITCHED CAPACITOR MASK PROGRAMMABLE FILTER

- 8TH ORDER
- SELECTIVITY FACTOR : $Q = 35$
- GAIN AT CENTER FREQUENCY : 30dB (typ)
- LOW STOPBAND ATTENUATION : 70dB (typ)
- HIGH STOPBAND ATTENUATION : 70dB (typ)
- CLOCK TO CENTER FREQ. RATIO : 187.2
- CLOCK FREQUENCY RANGE : 4 TO 3800kHz
- CENTER FREQUENCY RANGE : 22Hz TO 20.3kHz

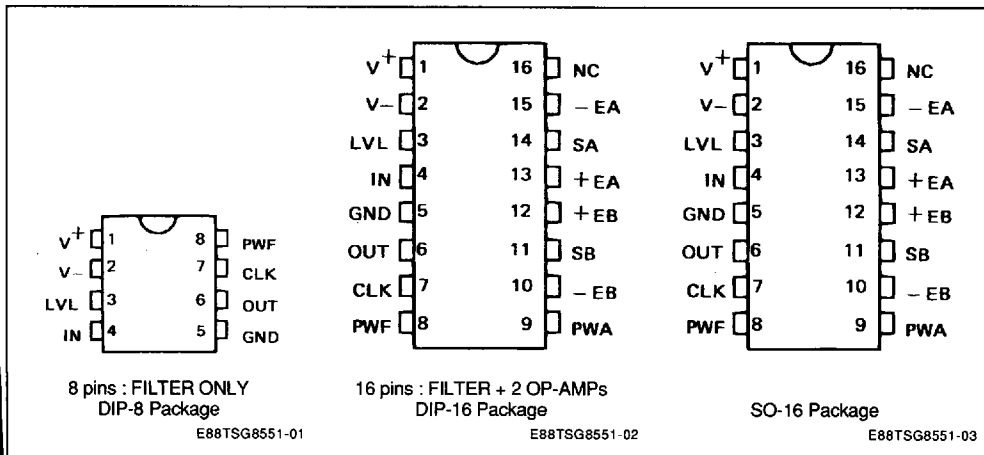
Note : For general characteristics, see TSG85XX specifications. For non standard quality level, consult SGS-THOMSON general ordering information.



DESCRIPTION

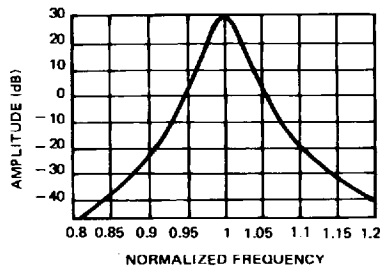
The TSG8551 is a HCMOS high selectivity band-pass filter.

PIN CONNECTIONS



AMPLITUDE RESPONSE CURVE

S G S-THOMSON



E88TSG8551-04

FILTER SPECIFICATIONS

Bandpass Filter : TSG8551 ; Type : High Q ; Order : 8.

 $V^+ = 5V$, $V^- = -5V$, $T = 25^\circ C$, $R_L = 5k\Omega$, $C_L = 100pF$, $I_{PWF} = 100\mu A$

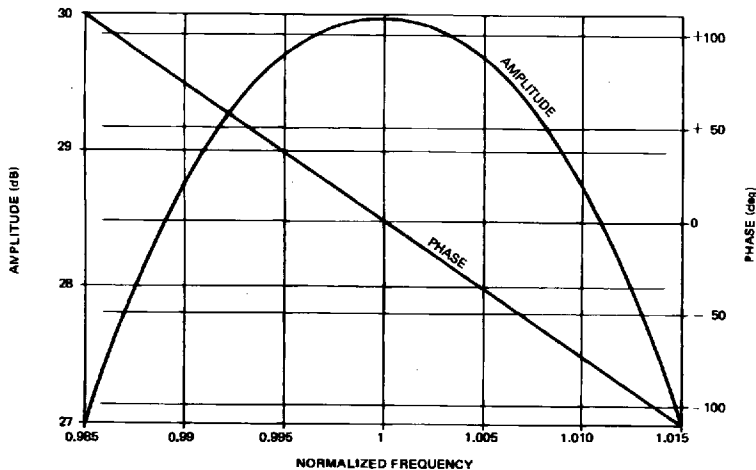
Symbol	Parameter		Typ.	Tested Limits	Unit
Fe	External Clock Frequency		4 3800(*)		kHz (min) kHz (max)
Fi	Internal Sampling Frequency		0.5 475(*)		kHz (min) kHz (max)
Fe/Fo	Clock to Center Ratio		187.2 ± 1%		
Fo	Center Frequency		0.022 20.3(*)		kHz (min) kHz (max)
Go	Gain at Center Frequency	Fe = 400kHz	30	32 28	dB (min) dB (max)
Q	Selectivity Coefficient		35		
Ap	Passband Ripple				dB (max)
Als	Low Stopband Attenuation	F < 0.8 Fo	70	55	dB (min)
Ahs	High Stopband Attenuation	F > 1.2 Fo	70	55	dB (min)
Voff	Output DC Offset Voltage	LVL = 0V	± 100	± 200	mV (max)
LVL	DC Level Adjustment		± 70		mV (max)
LG	Level gain		- 3.3		
R _{PWF}	PWF Resistance		10 72		KΩ (min) KΩ (max)
I _{PWF}	Input Current on PWF		50 250		μA (min) μA (max)
I*	V ⁺ Supply Current	Fe = 100kHz I _{pwa} = 0μA	3.8	5	mA (max)
I ⁻	V ⁻ Supply Current		3.8	5	mA (max)
PSRR ⁺	V ⁺ Supply Rejection Ratio	Fe = 187.2kHz Fin = 1kHz	10**		dB
PSRR ⁻	V ⁻ Supply Rejection Ratio		19**		dB
R _{IN}	Input Resistance		3		MΩ
C _{IN}	Input Capacitance		20		pF
Vo	Output Voltage Swing		+ 3.5 - 4.5		Vp-p (max)
Vn	Output Noise	BW = 3Hz Fe = 187.2kHz Vin = 2Vrms	56**		μVrms
SNR	Signal to Noise Ratio		90**		dB

* I_{PWF} = 200μA

** Value divided by the gain.

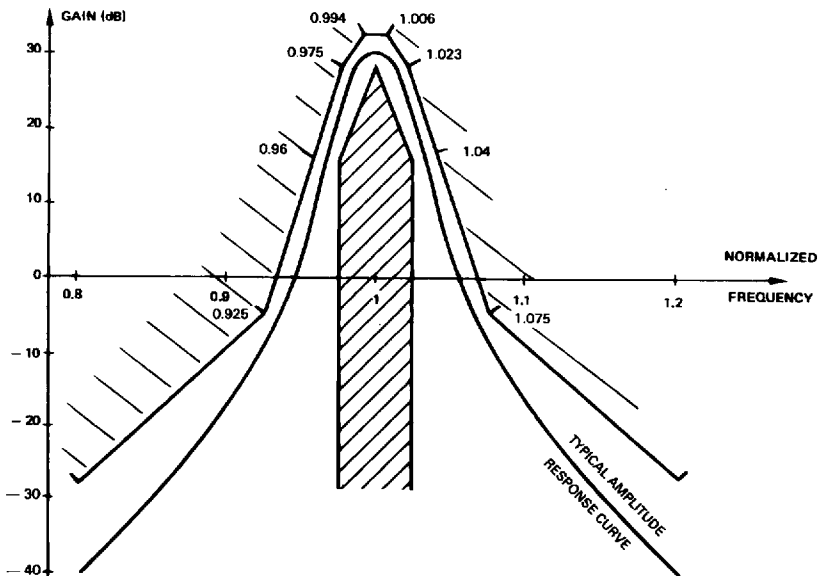
PHASE RESPONSE CURVE (in passband)

SGS-THOMSON



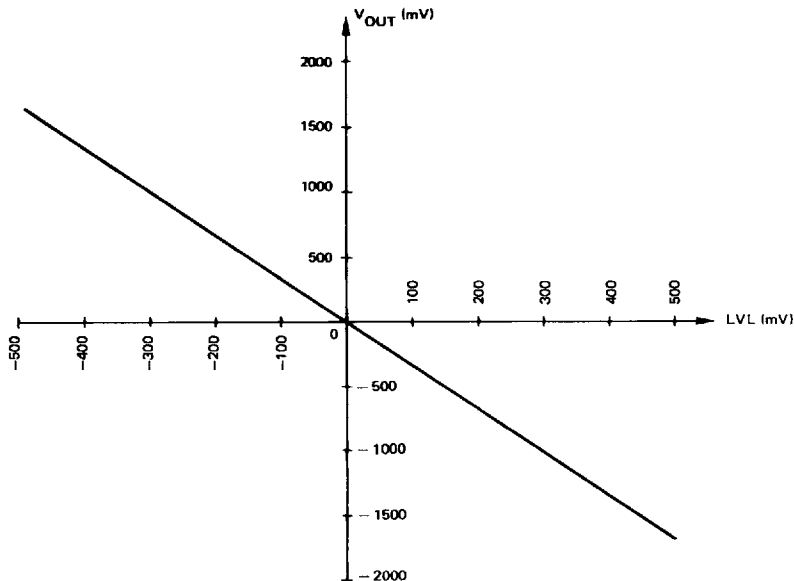
E88TSG8551-05

AMPLITUDE RESPONSE TEMPLATE (tested)



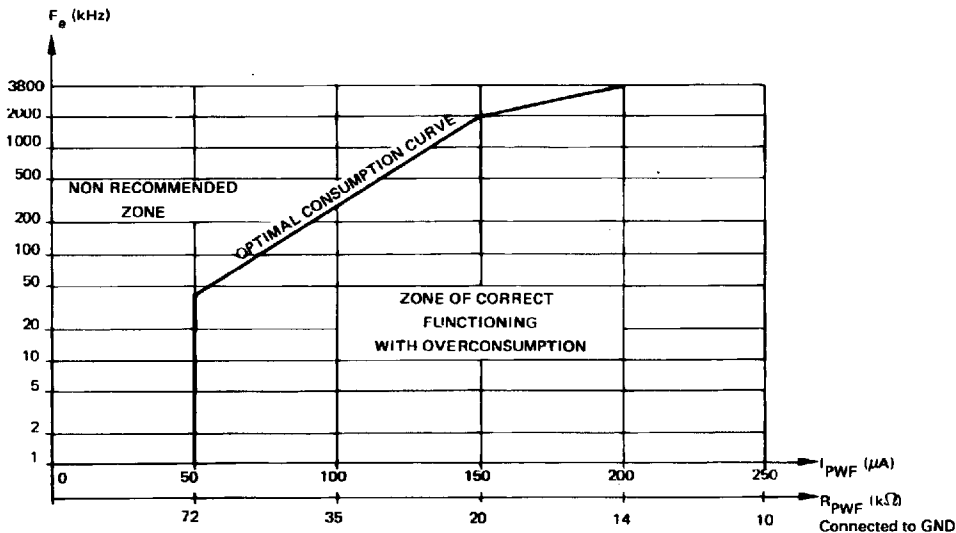
E88TSG8551-06

OUTPUT DC VOLTAGE ADJUSTMENT FROM LVL PIN



E88TSG8551-07

USER'S GUIDE FOR I_{PWF} AND R_{PWF} CHOICE

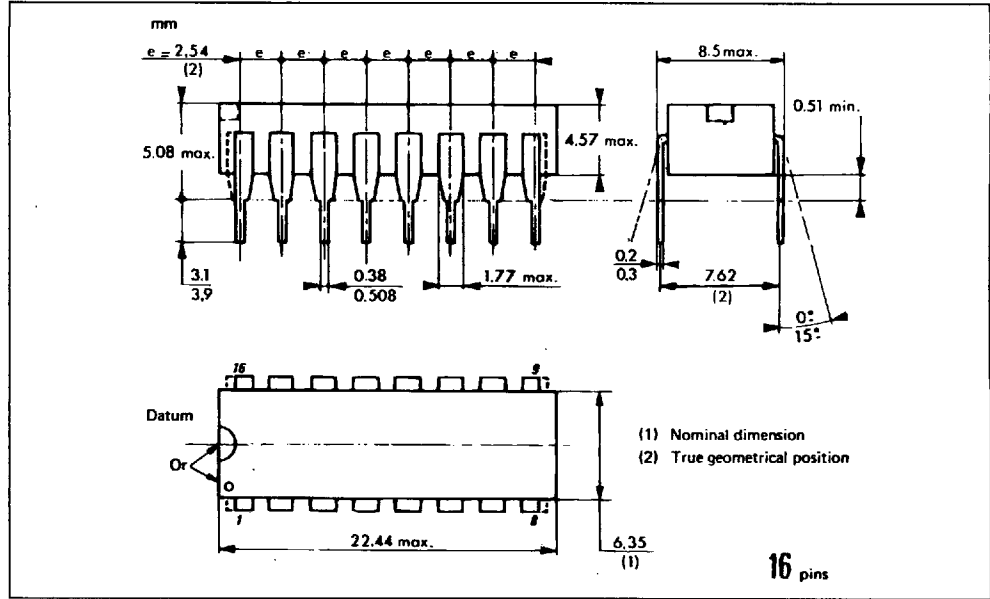


E88TSG8551-08

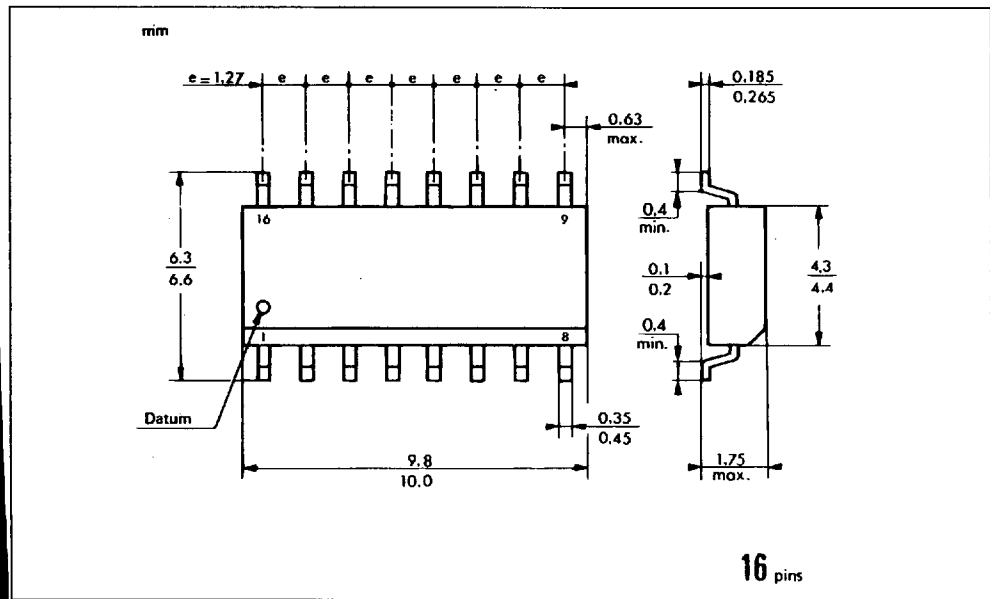
PACKAGE MECHANICAL DATA

S G S-THOMSON

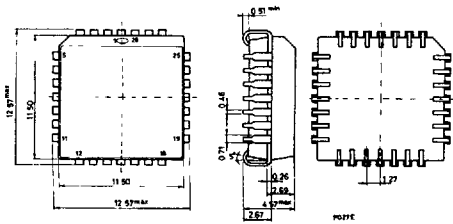
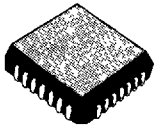
16 PINS - Plastic Dip



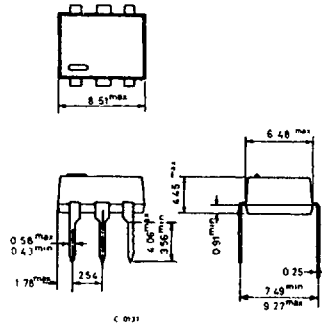
16 PINS - Plastic Micropackage



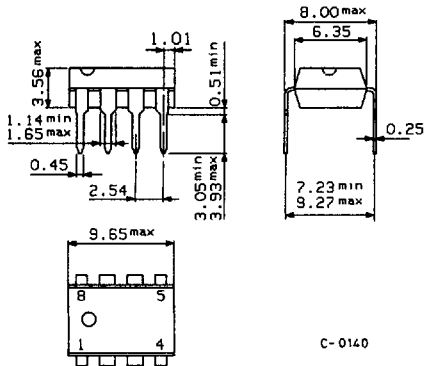
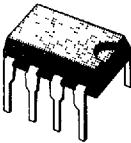
PLCC-28 Plastic Chip Carrier



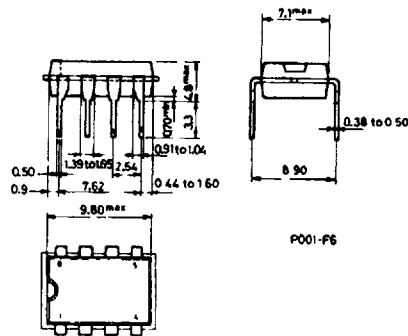
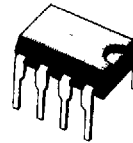
DIP-6



Minidip A Plastic

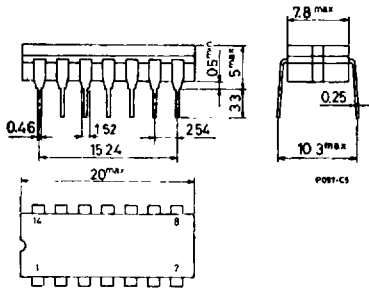
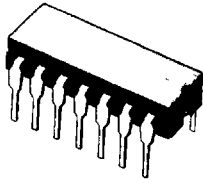


8 lead Plastic Minidip



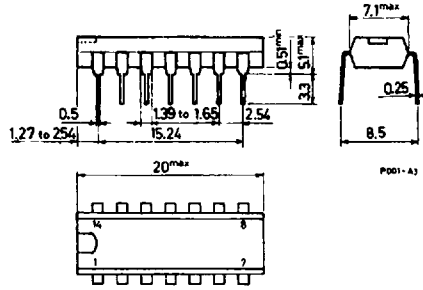
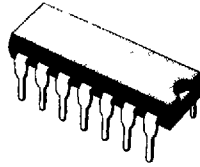
S G S-THOMSON

14 lead Ceramic Dip



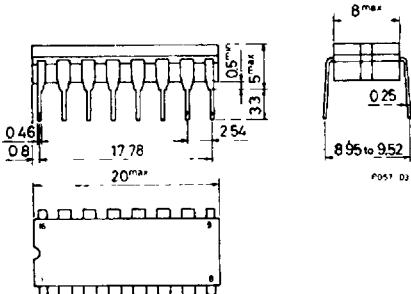
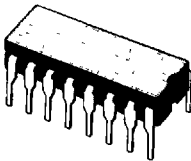
POD1-C3

14 lead Plastic Dip



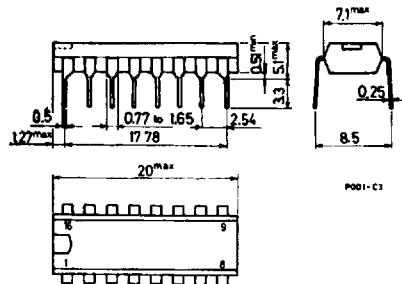
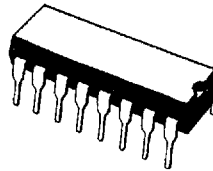
POD1-A3

16 lead Ceramic Dip



PO51-D2

16 lead Plastic Dip (0.25)

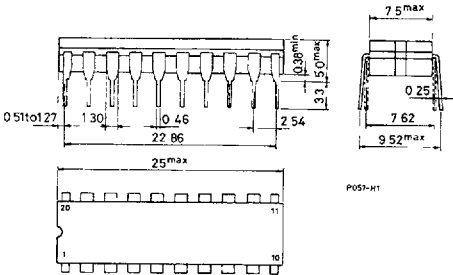
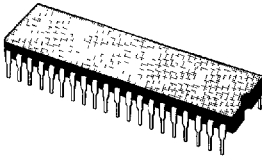


POD1-C3

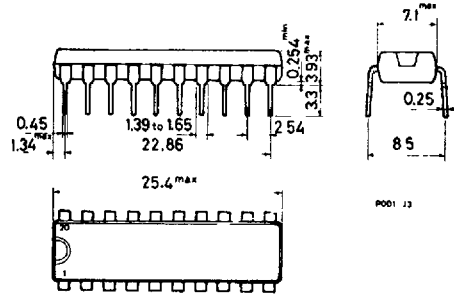
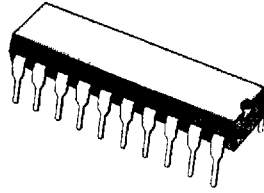
PACKAGES

S G S-THOMSON

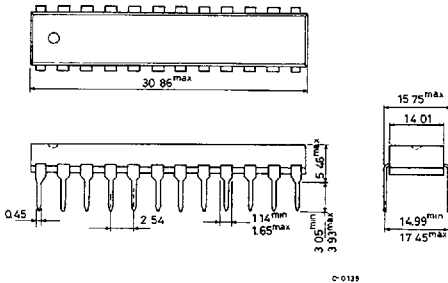
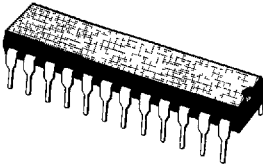
DIP-20 Ceramic



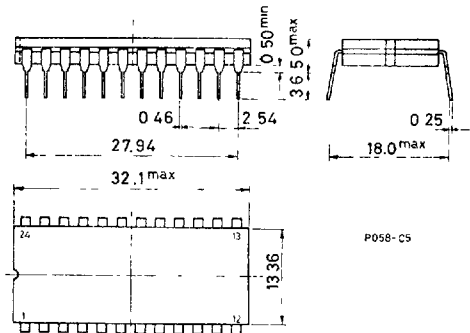
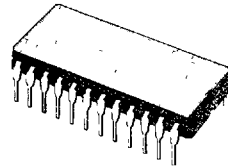
20 lead Plastic Dip (0.25)



DIP-24 Plastic

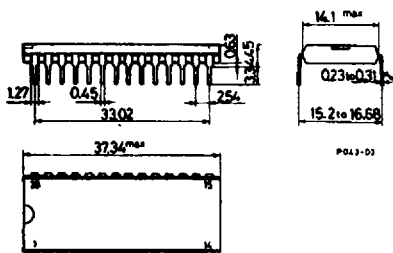
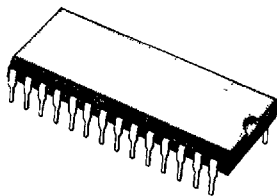


DIP-24 Ceramic (0.25)

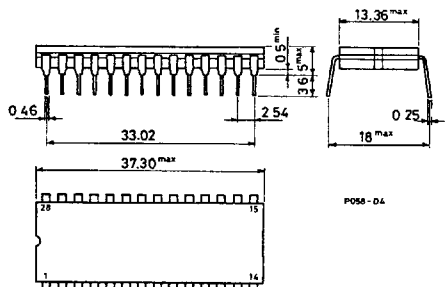
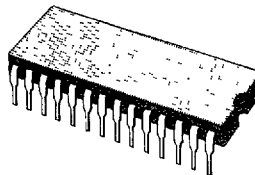


S G S-THOMSON

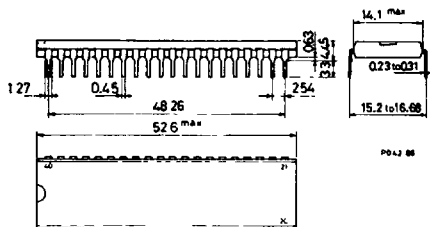
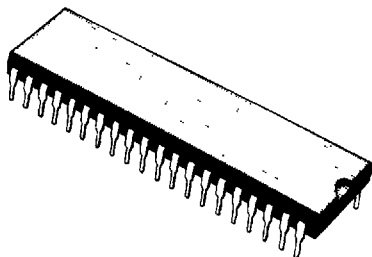
28 lead Plastic Dip



DIP-28 Ceramic (0.25)



40 lead Plastic Dip



TO-99

